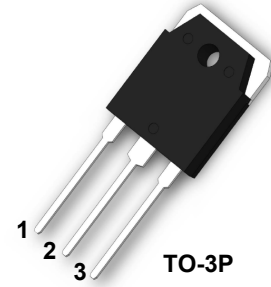


## PRODUCT FEATURES

- Ultrafast Recovery Time
- Low Recovery Loss
- Soft Reverse Recovery Characteristics
- Low Leakage Current
- Low Forward Voltage
- High Surge Current Capability

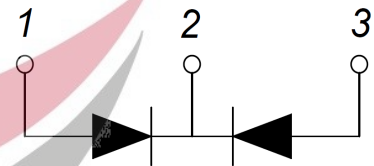
## APPLICATIONS

- Freewheeling, Snubber, Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS



## DESCRIPTION

FRED from MacMic utilizes advanced processing techniques to achieve ultrafast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.



## ABSOLUTE MAXIMUM RATINGS

$T_C = 25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter/Test Conditions		Values	Unit
$V_R$	Maximum D.C. Reverse Voltage		220	V
$V_{RRM}$	Maximum Repetitive Reverse Voltage			
$I_{F(AV)}$	Average Forward Current	$T_C = 110^\circ\text{C}$ , Per Diode	10	A
		$T_C = 110^\circ\text{C}$ , Per Package	20	
$I_{F(RMS)}$	RMS Forward Current	$T_C = 110^\circ\text{C}$ , Per Diode	14	
$I_{FSM}$	Non Repetitive Surge Forward Current	$T_J = 25^\circ\text{C}$ , $t = 10\text{ms}$ , 50Hz, Sine	150	
$P_D$	Power Dissipation		83	W
$T_J$	Junction Temperature		-55 to +150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range		-55 to +125	$^\circ\text{C}$
Torque	To Heat Sink	Recommended (M3)	1.1	Nm
$R_{thJC}$	Junction to Case Thermal Resistance( Per Diode )		1.5	$^\circ\text{C}/\text{W}$
Weight			6	g

## ELECTRICAL CHARACTERISTICS

$T_C = 25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter/Test Conditions		Min.	Typ.	Max.	Unit
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 220\text{V}$			10	$\mu\text{A}$
		$V_R = 220\text{V}$ , $T_J = 125^\circ\text{C}$			1	mA
$V_F$	Forward Voltage	$I_F = 10\text{A}$		0.9	1.2	V
		$I_F = 10\text{A}$ , $T_J = 125^\circ\text{C}$		0.8		
$trr$	Reverse Recovery Time ( $I_F = 1\text{A}$ , $di_F/dt = -200\text{A}/\mu\text{s}$ , $V_R = 30\text{V}$ )			17	21	ns
$trr$	Reverse Recovery Time ( $I_F = 0.5\text{A}$ , $I_R = 1\text{A}$ , $I_{RR} = 0.25\text{A}$ )			20	30	ns
$trr$	Reverse Recovery Time	$I_F = 10\text{A}$ , $V_R = 100\text{V}$ , $di_F/dt = -200\text{A}/\mu\text{s}$		20		ns
$I_{RRM}$	Maximum Reverse Recovery Current			2		A
$trr$	Reverse Recovery Time	$I_F = 10\text{A}$ , $V_R = 100\text{V}$ , $di_F/dt = -200\text{A}/\mu\text{s}$ , $T_J = 125^\circ\text{C}$		40		ns
$I_{RRM}$	Maximum Reverse Recovery Current			4		A

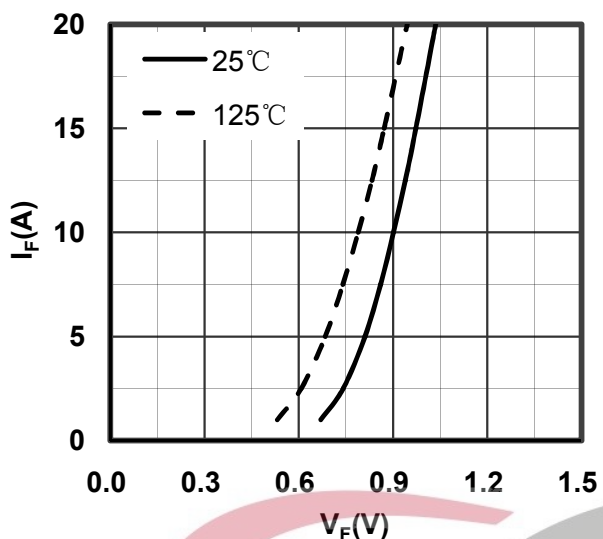


Figure 1. Forward Voltage Drop vs Forward Current

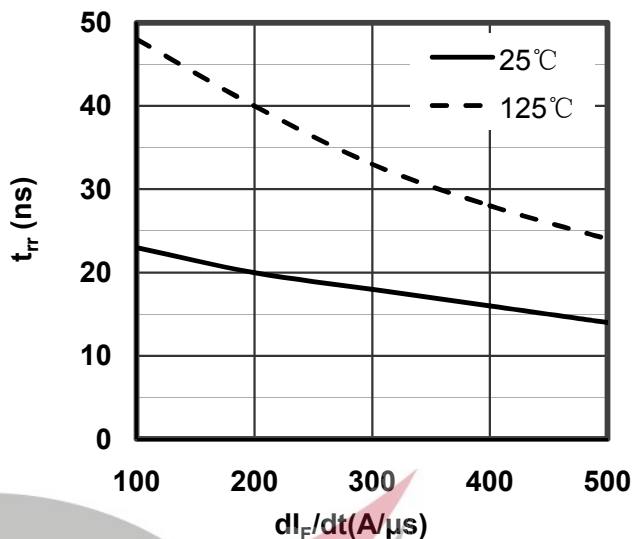


Figure 2. Reverse Recovery Time vs  $di_F/dt$

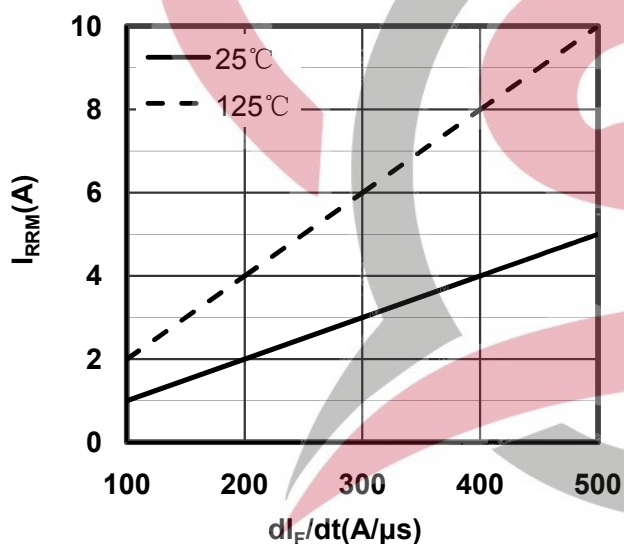


Figure 3. Reverse Recovery Current vs  $di_F/dt$

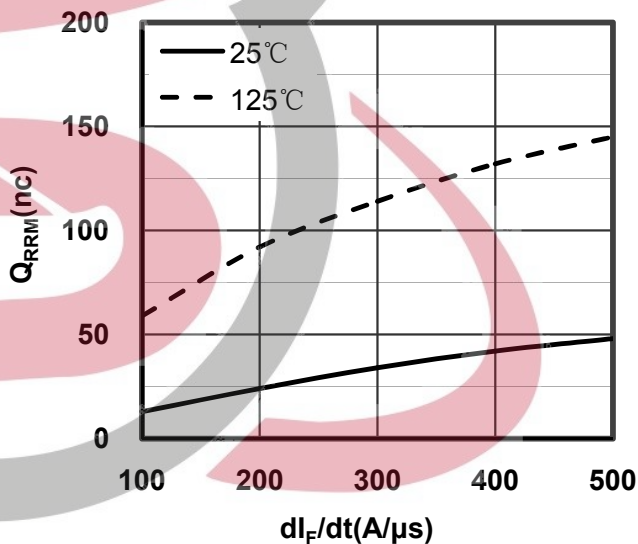


Figure 4. Reverse Recovery Charge vs  $di_F/dt$

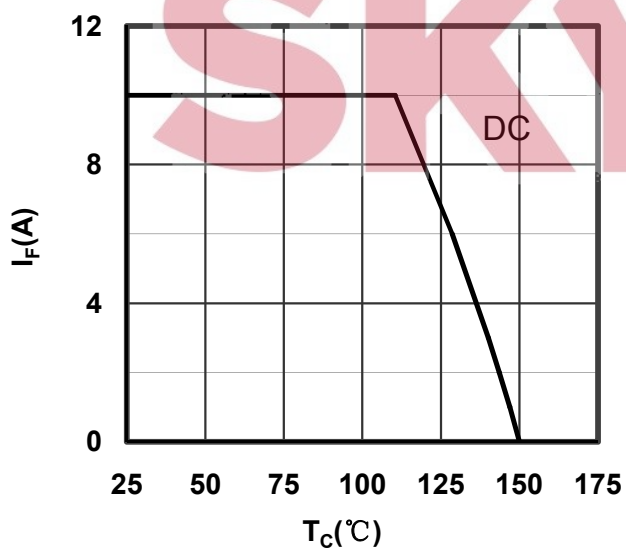


Figure 5. Forward current vs Case temperature

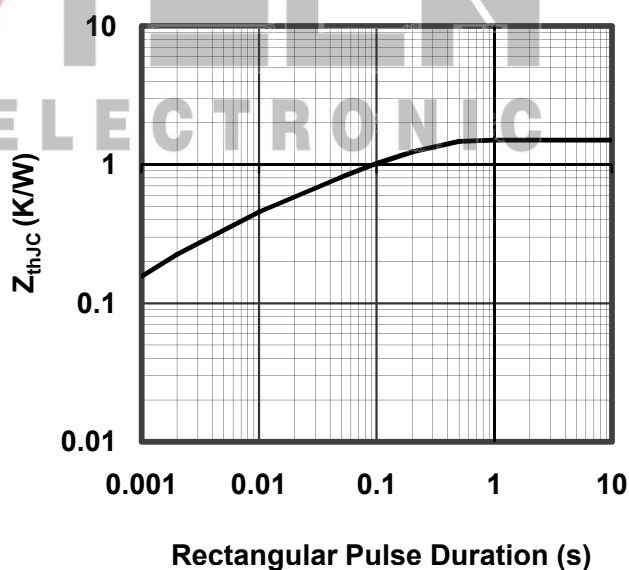


Figure 6. Transient Thermal Impedance

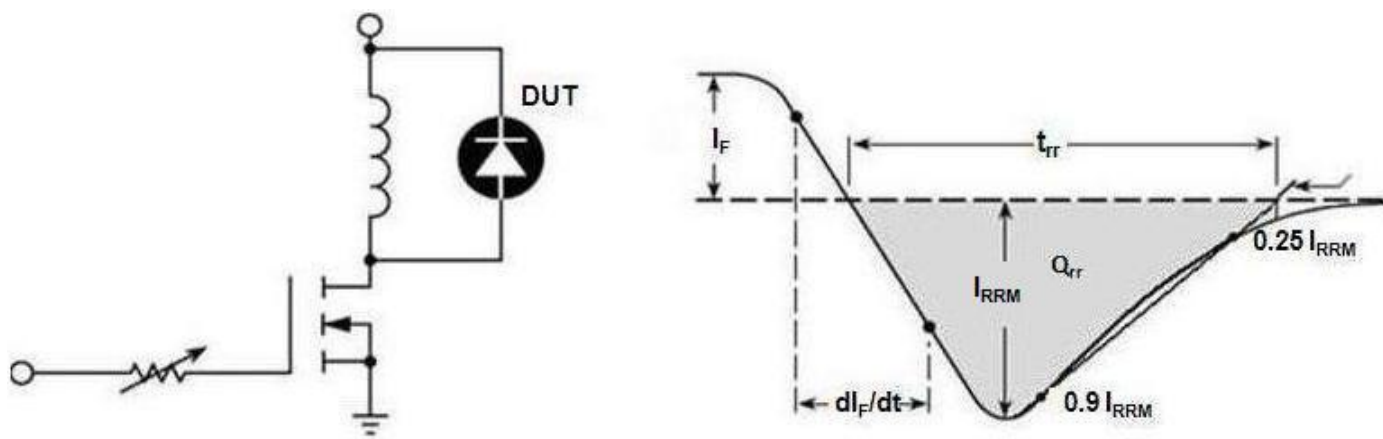
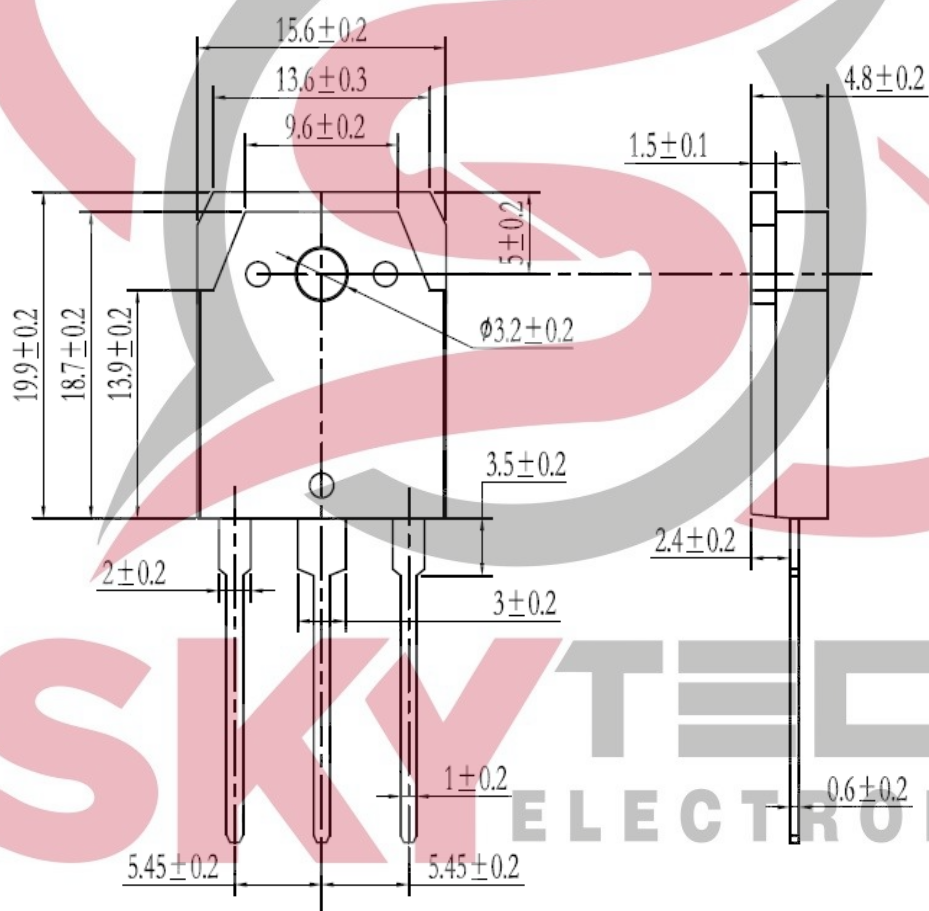


Figure 7. Diode Reverse Recovery Test Circuit and Waveform



Dimensions in (mm)  
Figure 8. Package Outline